80 V, 1 A NPN medium power transistors Rev. 9 — 25 October 2011

1. **Product profile**

1.1 General description

NPN medium power transistor series in Surface-Mounted Device (SMD) plastic packages.

Product overview Table 1.

| Type number ^[1] | Package | Package | | | | |
|----------------------------|---------|---------|--------|--------|--|--|
| | NXP | JEITA | JEDEC | | | |
| BCP56 | SOT223 | SC-73 | - | BCP53 | | |
| BCX56 | SOT89 | SC-62 | TO-243 | BCX53 | | |
| BC56PA | SOT1061 | - | - | BC53PA | | |

[1] Valid for all available selection groups.

1.2 Features and benefits

- High current
- Three current gain selections
- High power dissipation capability
- Exposed heatsink for excellent thermal and electrical conductivity (SOT89, SOT1061)
- Leadless very small SMD plastic package with medium power capability (SOT1061)
- AEC-Q101 gualified

1.3 Applications

- Linear voltage regulators
- Low-side switches
- Battery-driven devices
- Power management
- MOSFET drivers
- Amplifiers

1.4 Quick reference data

Table 2. Quick reference data

| Symbol | Parameter | Conditions | Min | Тур | Мах | Unit |
|-----------------|-------------------------------|--|----------------|-----|-----|------|
| V_{CEO} | collector-emitter voltage | open base | - | - | 80 | V |
| I _C | collector current | | - | - | 1 | А |
| I _{CM} | peak collector current | single pulse; $t_p \le 1 \text{ ms}$ | - | - | 2 | А |
| h _{FE} | DC current gain | $V_{CE} = 2 \text{ V}; I_{C} = 150 \text{ mA}$ | <u>[1]</u> 63 | - | 250 | |
| | h _{FE} selection -10 | $V_{CE} = 2 \text{ V}; I_{C} = 150 \text{ mA}$ | <u>[1]</u> 63 | - | 160 | |
| | h _{FE} selection -16 | $V_{CE} = 2 \text{ V}; I_{C} = 150 \text{ mA}$ | <u>[1]</u> 100 | - | 250 | |

[1] Pulse test: $t_p \le 300 \ \mu s$; $\delta = 0.02$.



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2. Pinning information

| Pin | Description | Simplified outline | Graphic symbol |
|---------|-------------|------------------------------|----------------|
| SOT223 | | | |
| 1 | base | | |
| 2 | collector | | 2,4 |
| 3 | emitter | | 1 |
| 4 | collector | | 3 sym016 |
| SOT89 | | | Symoro |
| 1 | emitter | | |
| 2 | collector | | 2 J |
| 3 | base | | 31 sym042 |
| SOT1061 | | | |
| 1 | base | | _ |
| 2 | emitter | 3 | 3 |
| 3 | collector | | 1 |
| | | 1 2 Transparent top view | sym021 |

3. Ordering information

| Table 4. Order | ing inform | ation | | | | | | |
|----------------------------|------------|--|---------|--|--|--|--|--|
| Type number ^[1] | Package | Package | | | | | | |
| | Name | Description | Version | | | | | |
| BCP56 | SC-73 | plastic surface-mounted package with increased heatsink; 4 leads | SOT223 | | | | | |
| BCX56 | SC-62 | plastic surface-mounted package; exposed die pad for good heat transfer; 3 leads | SOT89 | | | | | |
| BC56PA | HUSON3 | plastic thermal enhanced ultra thin small outline package; no leads; 3 terminals; body $2 \times 2 \times 0.65$ mm | SOT1061 | | | | | |

[1] Valid for all available selection groups.

BCP56_BCX56_BC56PA

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4. Marking

| Table 5. Marking codes | |
|--------------------------|--------------|
| Type number | Marking code |
| BCP56 | BCP56 |
| BCP56-10 | BCP56/10 |
| BCP56-16 | BCP56/16 |
| BCX56 | ВН |
| BCX56-10 | ВК |
| BCX56-16 | BL |
| BC56PA | AZ |
| BC56-10PA | ВК |
| BC56-16PA | BL |

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5. Limiting values

| Symbol | Parameter | Conditions | Min | Max | Unit |
|------------------|---------------------------|--|--------------|------|------|
| V _{CBO} | collector-base voltage | open emitter | - | 100 | V |
| V _{CEO} | collector-emitter voltage | open base | - | 80 | V |
| V _{EBO} | emitter-base voltage | open collector | - | 5 | V |
| l _C | collector current | | - | 1 | А |
| I _{CM} | peak collector current | single pulse; t _p ≤ 1 ms | - | 2 | A |
| I _B | base current | | - | 0.3 | А |
| I _{BM} | peak base current | single pulse; $t_p \le 1 \text{ ms}$ | - | 0.3 | А |
| P _{tot} | total power dissipation | $T_{amb} \le 25 \ ^{\circ}C$ | | | |
| | BCP56 | | <u>[1]</u> _ | 0.65 | W |
| | | | [2] | 1.00 | W |
| | | | [3] | 1.35 | W |
| | BCX56 | | <u>[1]</u> _ | 0.50 | W |
| | | | [2] | 0.95 | W |
| | | | <u>[3]</u> | 1.35 | W |
| | BC56PA | | <u>[1]</u> _ | 0.42 | W |
| | | | [2] | 0.83 | W |
| | | | [3] | 1.10 | W |
| | | | <u>[4]</u> _ | 0.81 | W |
| | | | <u>[5]</u> | 1.65 | W |
| Tj | junction temperature | | - | 150 | °C |
| T _{amb} | ambient temperature | | -55 | +150 | °C |
| T _{stg} | storage temperature | | -65 | +150 | °C |

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

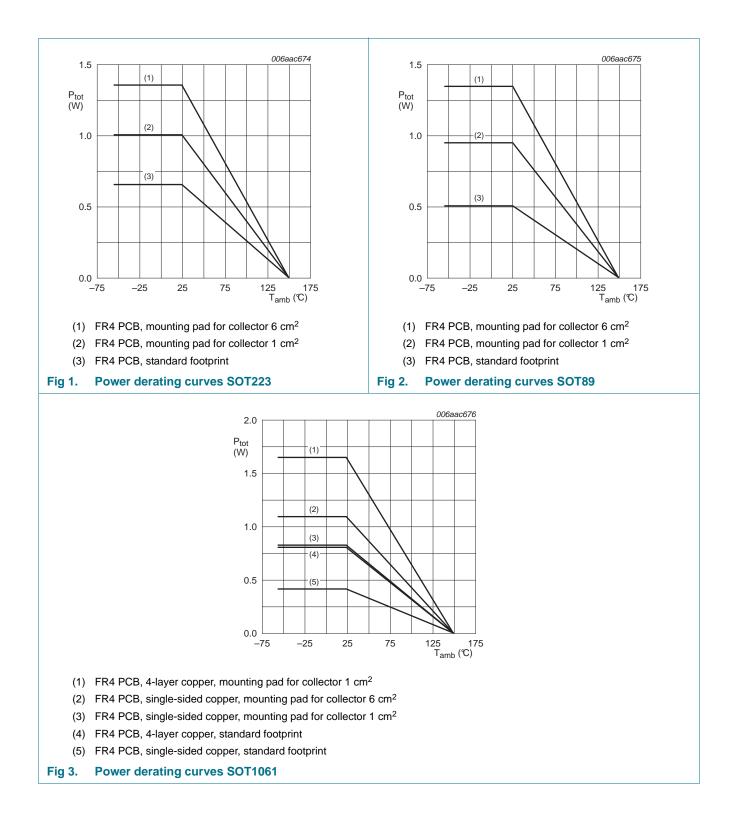
[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm².

[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm².

[4] Device mounted on an FR4 PCB, 4-layer copper, tin-plated and standard footprint.

[5] Device mounted on an FR4 PCB, 4-layer copper, tin-plated, mounting pad for collector 1 cm².

BCP56; BCX56; BC56PA



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6. Thermal characteristics

| Table 7. | Thermal characteristics | | | | | |
|-----------------------|---|-------------|--------------|-----|-----|------|
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
| R _{th(j-a)} | thermal resistance from junction to ambient | in free air | | | | |
| | BCP56 | | <u>[1]</u> - | - | 192 | K/W |
| | | | [2] _ | - | 125 | K/W |
| | | | [3] _ | - | 93 | K/W |
| | BCX56 | | <u>[1]</u> - | - | 250 | K/W |
| | | | [2] _ | - | 132 | K/W |
| | | | [3] _ | - | 93 | K/W |
| | BC56PA | | <u>[1]</u> - | - | 298 | K/W |
| | | | [2] _ | - | 151 | K/W |
| | | | [3] _ | - | 114 | K/W |
| | | | <u>[4]</u> _ | - | 154 | K/W |
| | | | [5] _ | - | 76 | K/W |
| R _{th(j-sp)} | thermal resistance from junction to solder point | | | | | |
| | BCP56 | | - | - | 16 | K/W |
| | BCX56 | | - | - | 16 | K/W |
| | BC56PA | | - | - | 20 | K/W |

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

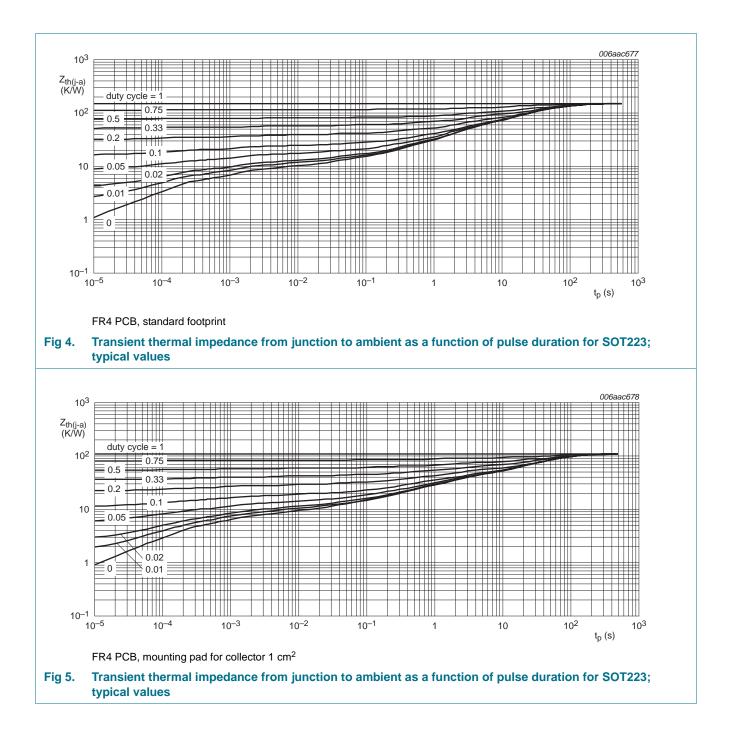
[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm².

[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm².

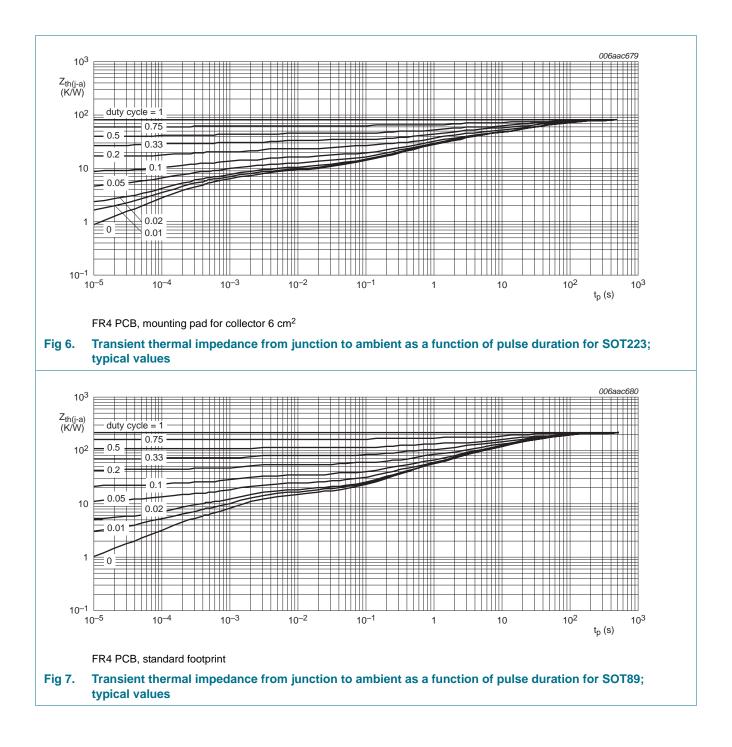
[4] Device mounted on an FR4 PCB, 4-layer copper, tin-plated and standard footprint.

[5] Device mounted on an FR4 PCB, 4-layer copper, tin-plated, mounting pad for collector 1 cm².

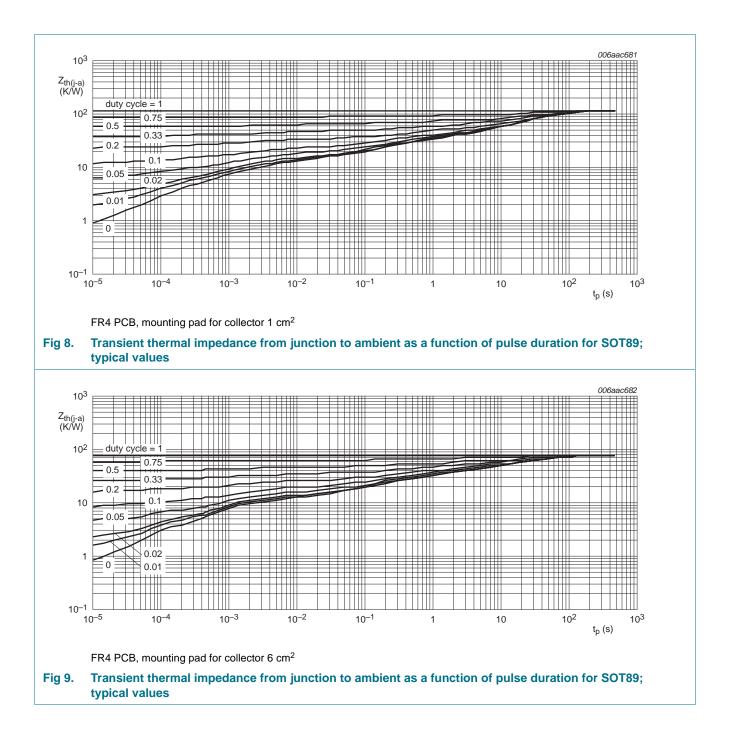
BCP56; BCX56; BC56PA



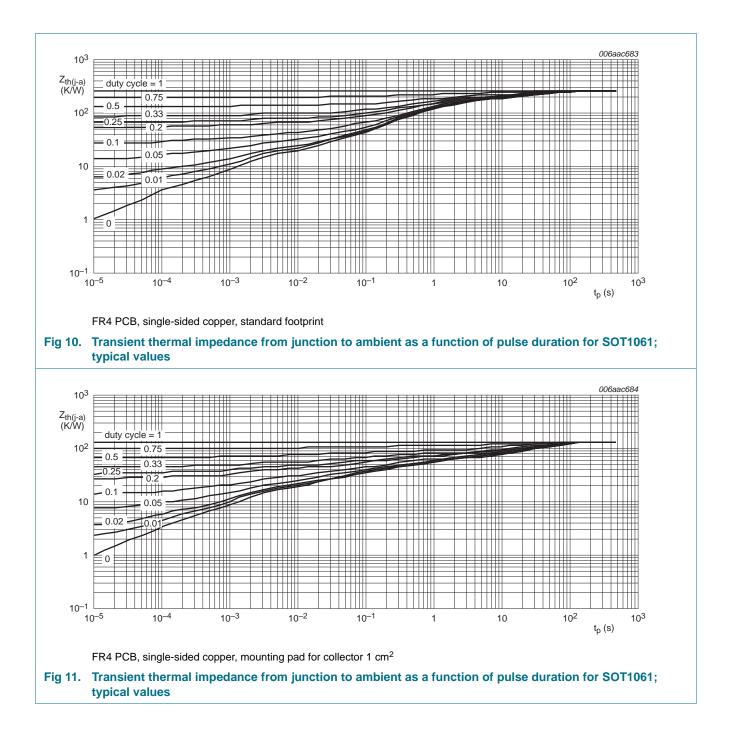
BCP56; BCX56; BC56PA



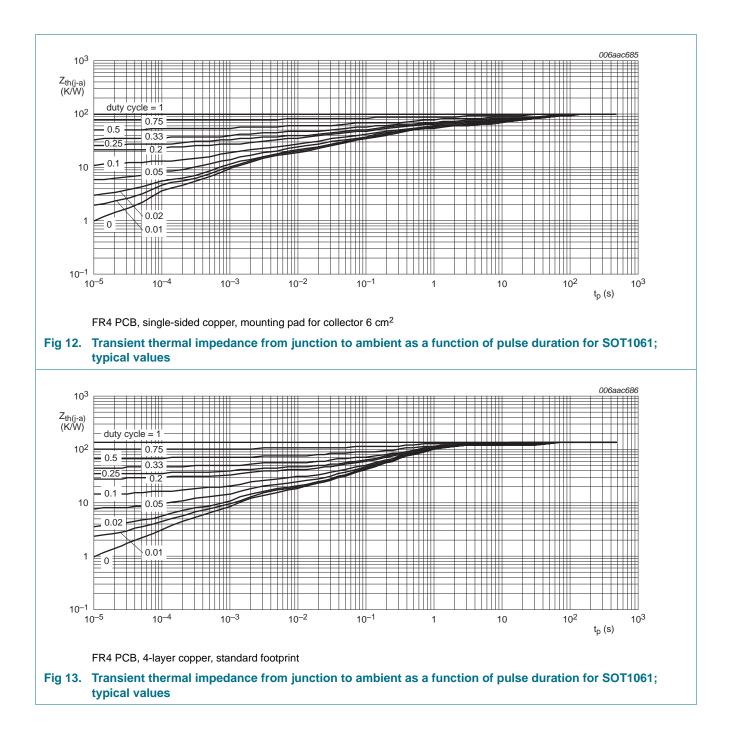
BCP56; BCX56; BC56PA



BCP56; BCX56; BC56PA

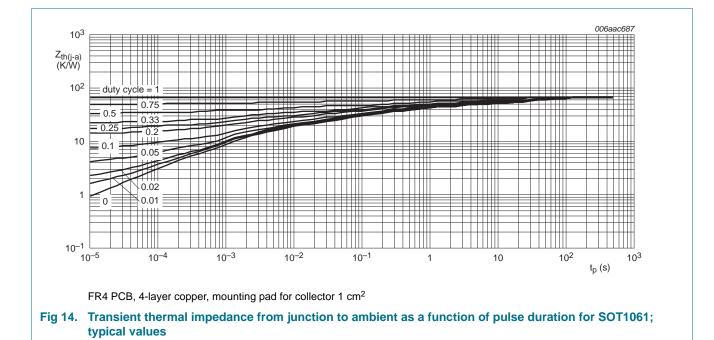


BCP56; BCX56; BC56PA



BCP56; BCX56; BC56PA

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7. Characteristics

Table 8.Characteristics

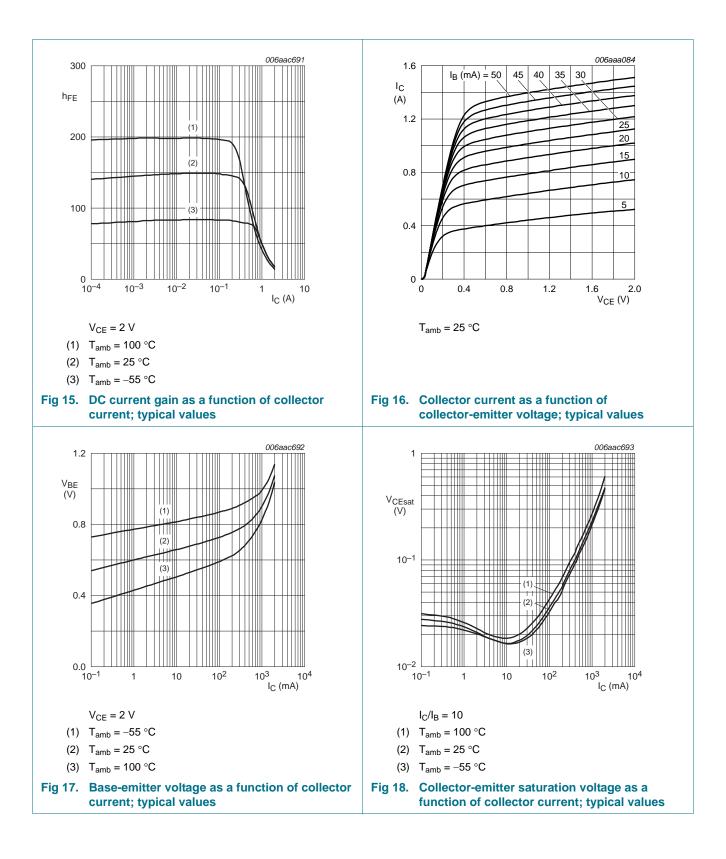
 $T_{amb} = 25 \ ^{\circ}C$ unless otherwise specified.

| Symbol | Parameter | Conditions | Mir | п Тур | Мах | Unit |
|---------------------------------|--------------------------------------|--|---------------------|-------|-----|------|
| I _{CBO} | collector-base cut-off | $V_{CB} = 30 \text{ V}; I_E = 0 \text{ A}$ | - | - | 100 | nA |
| | current | $\label{eq:VCB} \begin{array}{l} V_{CB} = 30 \ V; \ I_{E} = 0 \ A; \\ T_{j} = 150 \ ^{\circ}C \end{array}$ | - | - | 10 | μΑ |
| I _{EBO} | emitter-base cut-off current | $V_{EB} = 5 \text{ V}; \text{ I}_{C} = 0 \text{ A}$ | - | - | 100 | nA |
| h _{FE} DC current gain | | $V_{CE} = 2 V$ | | | | |
| | | $I_{\rm C} = 5 \rm{mA}$ | <u>[1]</u> 63 | - | - | |
| | | I _C = 150 mA | <u>[1]</u> 63 | - | 250 | |
| DC current gain | I _C = 500 mA | <u>[1]</u> 40 | - | - | | |
| | $V_{CE} = 2 V$ | | | | | |
| | h _{FE} selection -10 | I _C = 150 mA | <mark>[1]</mark> 63 | - | 160 | |
| | h _{FE} selection -16 | I _C = 150 mA | [<u>1]</u> 100 |) - | 250 | |
| V _{CEsat} | collector-emitter saturation voltage | $I_{\rm C}$ = 500 mA; $I_{\rm B}$ = 50 mA | <u>[1]</u> - | - | 0.5 | V |
| V _{BE} | base-emitter voltage | $V_{CE} = 2 \text{ V}; \text{ I}_{C} = 500 \text{ mA}$ | <u>[1]</u> - | - | 1 | V |
| C _c | collector capacitance | $\label{eq:VCB} \begin{array}{l} V_{CB} = 10 \text{ V}; \text{ I}_{E} = \text{i}_{e} = 0 \text{ A}; \\ \text{f} = 1 \text{ MHz} \end{array}$ | - | 6 | - | pF |
| f _T | transition frequency | V _{CE} = 5 V; I _C = 50 mA; f = 100 MHz | 100 |) 180 | - | MHz |

[1] Pulse test: $t_p \le 300 \ \mu$ s; $\delta = 0.02$.

BCP56; BCX56; BC56PA

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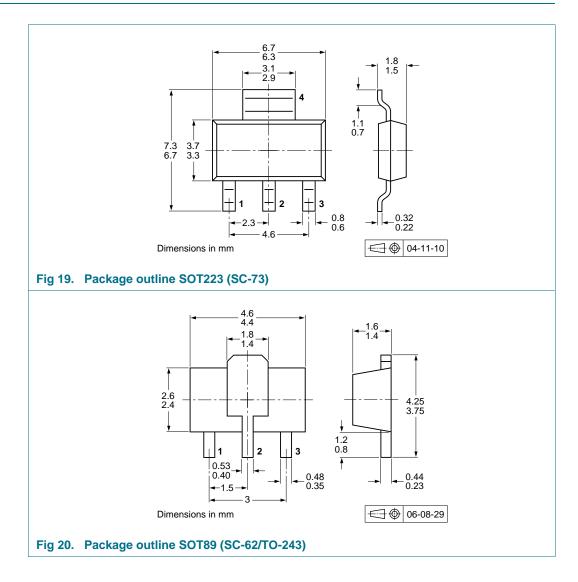
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8. Test information

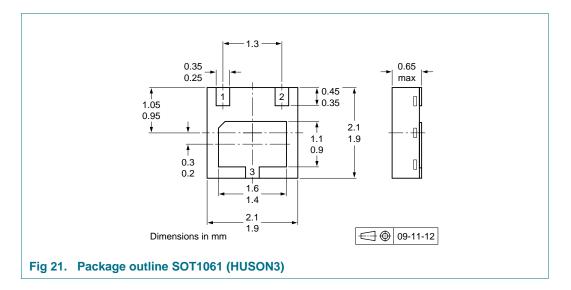
8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

9. Package outline



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10. Packing information

Table 9. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

| Туре | Package Description | | | Packin | g quant | ity |
|-----------------------|---------------------|-------------------------------------|-----|--------|---------|------|
| number ^[2] | | | | 1000 | 3000 | 4000 |
| BCP56 | SOT223 | 8 mm pitch, 12 mm tape and reel | | -115 | - | -135 |
| BCX56 SOT89 | | 8 mm pitch, 12 mm tape and reel; T1 | [3] | -115 | - | -135 |
| | | 8 mm pitch, 12 mm tape and reel; T3 | [4] | -146 | - | - |
| BC56PA | SOT1061 | 4 mm pitch, 8 mm tape and reel | | - | -115 | - |

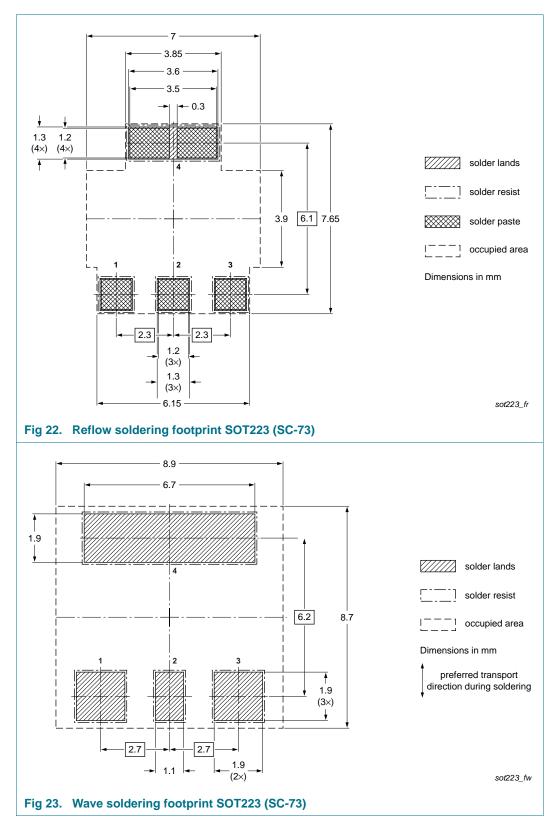
[1] For further information and the availability of packing methods, see <u>Section 14</u>.

[2] Valid for all available selection groups.

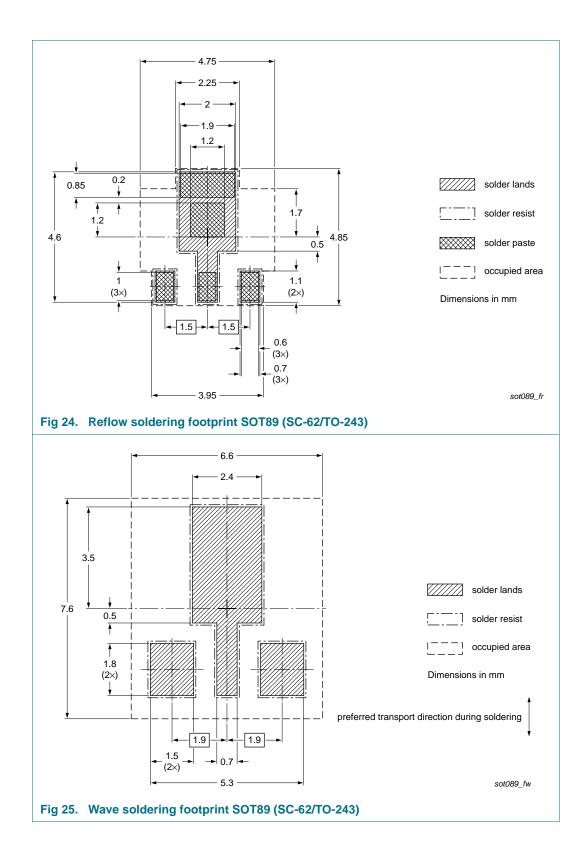
- [3] T1: normal taping
- [4] T3: 90° rotated taping

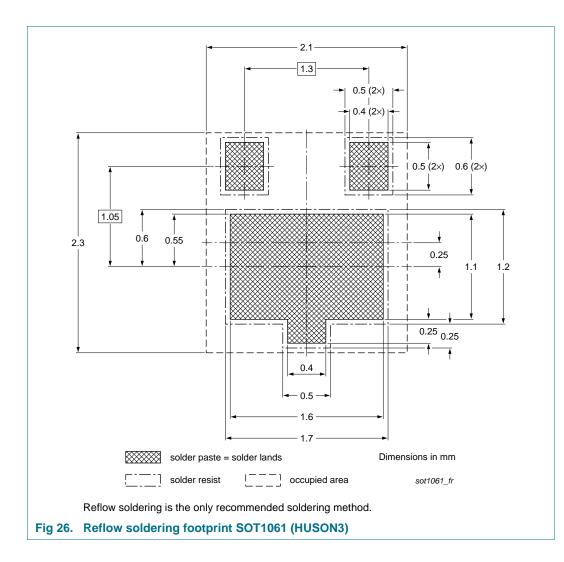
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11. Soldering



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12. Revision history

Table 10.Revision history

| 111025 | Data sheet status Product data sheet | Change notice | Supersedes BC639_BCP56_BCX56 v.8 | | | |
|--|---|---|---|--|--|--|
| | | - | BC639 BCP56 BCX56 v.8 | | | |
| Type numbe | | | | | | |
| | r removed: BC639 | | | | | |
| Type number added: BC56PA, BC56-10PA and BC56-16PA | | | | | | |
| Section 1 "Pi | roduct profile": updated | | | | | |
| Section 2 "Pi | inning information": update | ed | | | | |
| Table 6 and | 2: updated according to late | test measurement | s | | | |
| Figure 1, 2, 4 | <u>4, 5, 7</u> to <u>9, 15, 17</u> and <u>18</u> : | updated | | | | |
| Figure 3, <u>6</u> , 1 | 10 to 14: added | | | | | |
| Section 8 "Te | est information": added | | | | | |
| Section 10 " | Packing information": upda | ated | | | | |
| Section 11 "S | Soldering": added | | | | | |
| Section 13 "L | <u>egal information</u> : update | d | | | | |
| 070622 | Product data sheet | - | BC639_BCP56_BCX56 v.7 | | | |
| 050308 | Product data sheet | - | BC639_BCP56_BCX56 v.6 | | | |
| 050303 | Product data sheet | CPCN2004050 | BC635_637_639 v.4 | | | |
| | | 29 | BCP54_55_56 v.5 | | | |
| | | | BCX54_55_56 v.4 | | | |
| 011010 | Product specification | - | BC635_637_639 v.3 | | | |
| 030206 | Product specification | - | BCP54_55_56 v.4 | | | |
| 011010 | Product specification | - | BCX54_55_56 v.3 | | | |
| | Section 2 "P Table 6 and Figure 1, 2, 4 Figure 3, 6, 7 Section 8 "Te Section 10 "I Section 11 "S Section 13 "I 070622 050308 050303 | Section 2 "Pinning information": updateTable 6and 7: updated according to latFigure 1, 2, 4, 5, 7 to 9, 15, 17 and 18:Figure 3, 6, 10 to 14: addedSection 8 "Test information": addedSection 10 "Packing information": updateSection 11 "Soldering": addedSection 13 "Legal information": update070622Product data sheet050308Product data sheet050303Product specification011010Product specification030206Product specification | Section 2 "Pinning information": updated Table 6 and 7: updated according to latest measurement Figure 1, 2, 4, 5, 7 to 9, 15, 17 and 18: updated Figure 3, 6, 10 to 14: added Section 8 "Test information": added Section 10 "Packing information": updated Section 11 "Soldering": added Section 13 "Legal information": updated 070622 Product data sheet 070622 Product data sheet 050308 Product data sheet 050303 Product specification 011010 Product specification 030206 Product specification | | | |

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13. Legal information

13.1 Data sheet status

| Document status[1][2] | Product status ^[3] | Definition |
|--------------------------------|-------------------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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